SOT-23 MULTILED®, Diffused

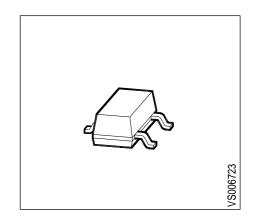
LU S250, LV S260, LW S260

Besondere Merkmale

- eingefärbtes, diffuses Gehäuse
- extrem weitwinklig
- als optischer Indikator einsetzbar
- für alle SMT-Bestück- und Löttechniken geeignet
- beide Farben getrennt ansteuerbar
- gegurtet (8-mm-Filmgurt)
- Störimpulsfest nach DIN 40838

Features

- colored, diffused package
- extreme wide-angle LED
- for use as optical indicator
- suitable for all SMT assembly and soldering methods
- both colors can be controlled separately
- available taped on reel (8 mm tape)
- load dump resistant acc. to DIN 40839



| Typ Type | Emissionsfarbe Color of Emission | Gehäusefarbe Color of Package | Lichtstärke Luminous Intensity $I_{\rm F}$ = 10 mA $I_{\rm V}$ (mcd) | Bestellnummer Ordering Code |
|-------------|--|-------------------------------------|--|--------------------------------|
| LU S250-DO | super-red/green | colorless diffused | ≥ 0.4 | Q62703-Q1642 |
| LV S260-DO | super-red/ super-red | red diffused | ≥ 0.4 | Q62703-Q2067 |
| LW S260-DO | green/green | green diffused | ≥ 0.4 | Q62703-Q1038 |

Streuung der Lichtstärke in einer Verpackungseinheit $I_{\text{V max}}$ / $I_{\text{V min}} \leq 2.0$. Luminous intensity ratio in one packaging unit $I_{\text{V max}}$ / $I_{\text{V min}} \leq 2.0$.

Grenzwerte Maximum Ratings

| Bezeichnung Parameter | Symbol Symbol | Werte Values | Einheit Unit |
|--|------------------|-------------------|-----------------|
| Betriebstemperatur Operating temperature range | T_{op} | - 55 + 100 | C |
| Lagertemperatur Storage temperature range | $T_{ m stg}$ | - 55 + 100 | °C |
| Sperrschichttemperatur Junction temperature | T _j | + 100 | C |
| Durchlaßstrom Forward current | I_{F} | 30 | mA |
| Stoßstrom Surge current $t \le 10 \mu \text{s}, D = 0.005$ | I_{FM} | 0.5 | A |
| Sperrspannung Reverse voltage | V_{R} | 5 | V |
| Verlustleistung Power dissipation $T_A \le 25 ^{\circ}\text{C}$ | $P_{ m tot}$ | 100 | mW |
| Wärmewiderstand Thermal resistance Sperrschicht / Luft Junction / air ¹⁾ | R_{thJA} | 750 | K/W |

¹⁾ Auf Platine gelötet: Lötfläche \geq 16 cm².

Notes

Die angegebenen Grenzdaten gelten für einen Chip.

The stated maximum ratings refer to one chip.

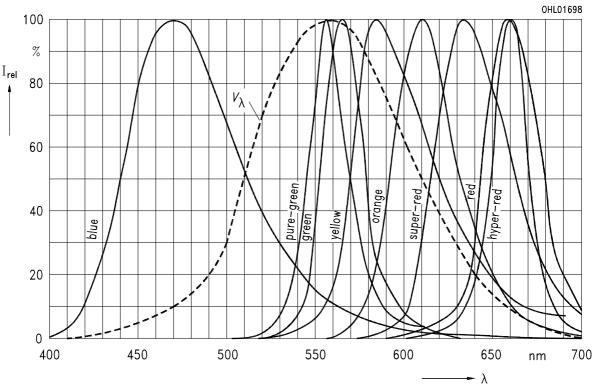
¹⁾ Soldered on PC board: pad size \geq 16 cm².

Kennwerte $(T_A = 25 \, ^{\circ}\text{C})$ **Characteristics**

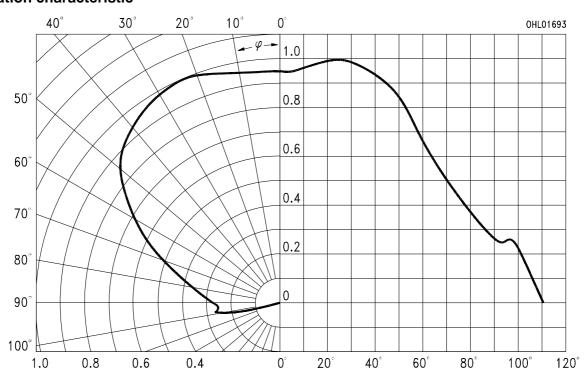
| Bezeichnung Parameter | | Symbol Symbol | Werte Values | | Einheit Unit |
|--|------------------|------------------|-----------------|--------------|-----------------|
| | | | super-red | green | |
| Wellenlänge des emittierten Lichtes Wavelength at peak emission $I_{\rm F}$ = 20 mA | (typ.) (typ.) | λ_{peak} | 635 | 565 | nm |
| Dominantwellenlänge Dominant wavelength $I_{\rm F}$ = 20 mA | (typ.) (typ.) | λ_{dom} | 628 | 570 | nm |
| Spektrale Bandbreite bei 50 % $I_{\rm relmax}$ Spectral bandwidth at 50 % $I_{\rm relmax}$ $I_{\rm F}$ = 20 mA | (typ.) (typ.) | Δλ | 45 | 25 | nm |
| Abstrahlwinkel bei 50 % I_{V} (Vollwinkel Viewing angle at 50 % I_{V} | 2φ | 140 | 140 | Grad deg. | |
| Durchlaßspannung Forward voltage $I_{\rm F} = 10 \text{ mA}$ | (typ.) (max.) | $V_{F} \ V_{F}$ | 2.0 2.6 | 2.0 2.6 | V V |
| Sperrstrom Reverse current $V_R = 5 \text{ V}$ | (typ.) (max.) | | 0.01 10 | 0.01 10 | μA μA |
| Kapazität (apacitance $V_{\rm R} = 0 \ {\rm V}, f = 1 \ {\rm MHz}$ | | C_0 | 12 | 15 | pF |
| Schaltzeiten: Switching times: $I_{\rm V} \ {\rm from} \ 10 \ \% \ {\rm to} \ 90 \ \% \qquad \qquad {\rm (typ.}$ $I_{\rm V} \ {\rm from} \ 90 \ \% \ {\rm to} \ 10 \ \% \qquad \qquad {\rm (typ.}$ $I_{\rm F} = 100 \ {\rm mA}, \ t_{\rm P} = 10 \ {\rm \mu s}, \ R_{\rm L} = 50 \ \Omega$ | | 1 - | 300 150 | 450 200 | ns ns |

Relative spektrale Emission $I_{\rm rel}$ = f (λ), $T_{\rm A}$ = 25 °C, $I_{\rm F}$ = 20 mA Relative spectral emission

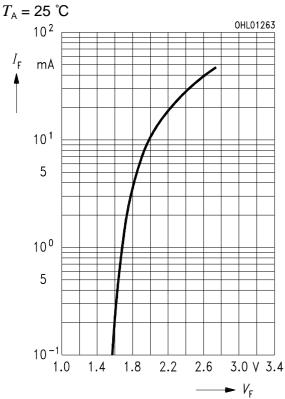
 $V(\lambda)$ = spektrale Augenempfindlichkeit Standard eye response curve



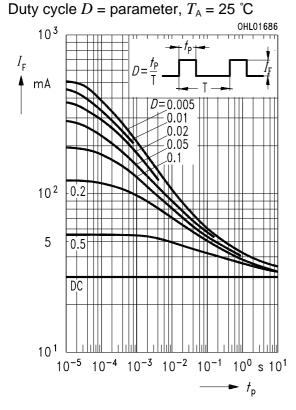
Abstrahlcharakteristik $I_{rel} = f(\phi)$ Radiation characteristic



Durchlaßstrom $I_F = f(V_F)$ Forward current

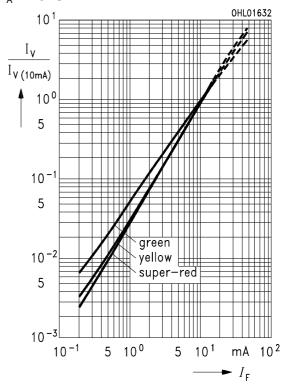


Zulässige Impulsbelastbarkeit $I_{\rm F} = f\left(t_{\rm P}\right)$ Permissible pulse handling capability

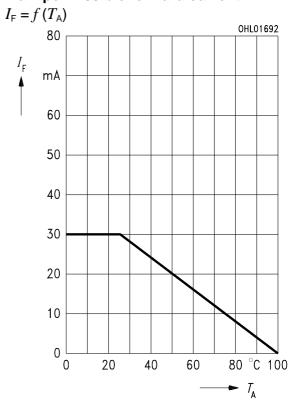


Relative Lichtstärke $I_V/I_{V(10 \text{ mA})} = f(I_F)$ Relative luminous intensity

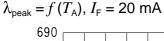
 $T_{\rm A} = 25 \,{\rm ^{\circ}C}$

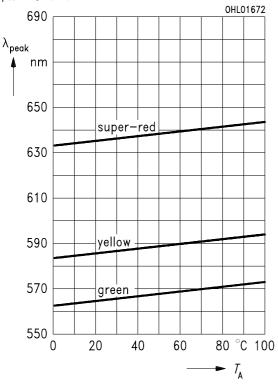


Maximal zulässiger Durchlaßstrom Max. permissible forward current



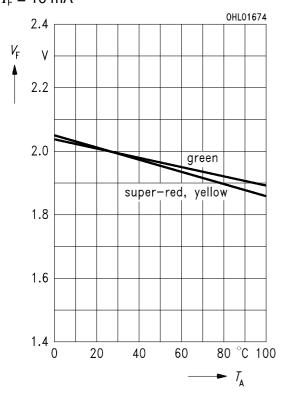
Wellenlänge der Strahlung Wavelength at peak emission





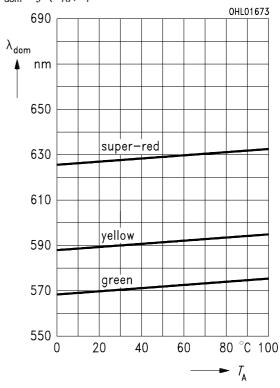
Durchlaßspannung $V_{\rm F} = f(T_{\rm A})$ Forward voltage

$$I_{\rm F}$$
 = 10 mA



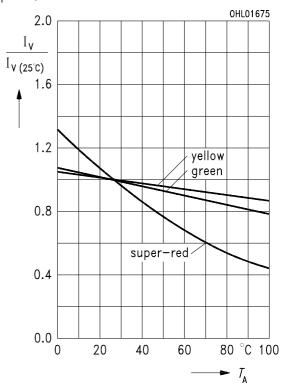
Dominantwellenlänge **Dominant wavelength**

 $\lambda_{\text{dom}} = f(T_{\text{A}}), I_{\text{F}} = 20 \text{ mA}$



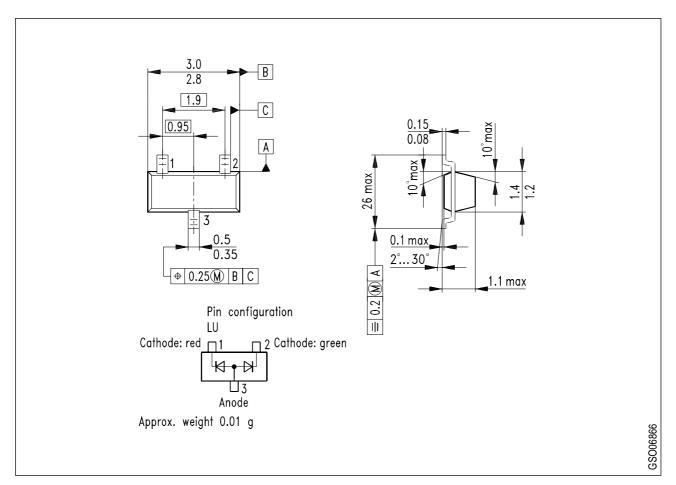
Relative Lichtstärke $I_{V}/I_{V(25~^{\circ}C)} = f(T_{A})$ **Relative luminous intensity**

 $I_{\rm F}$ = 10 mA



Maßzeichnung Package Outlines

(Maße in mm, wenn nicht anders angegeben) (Dimensions in mm, unless otherwise specified)



Anschlußbelegung: (Draufsicht) **Pin configuration:** (top view)